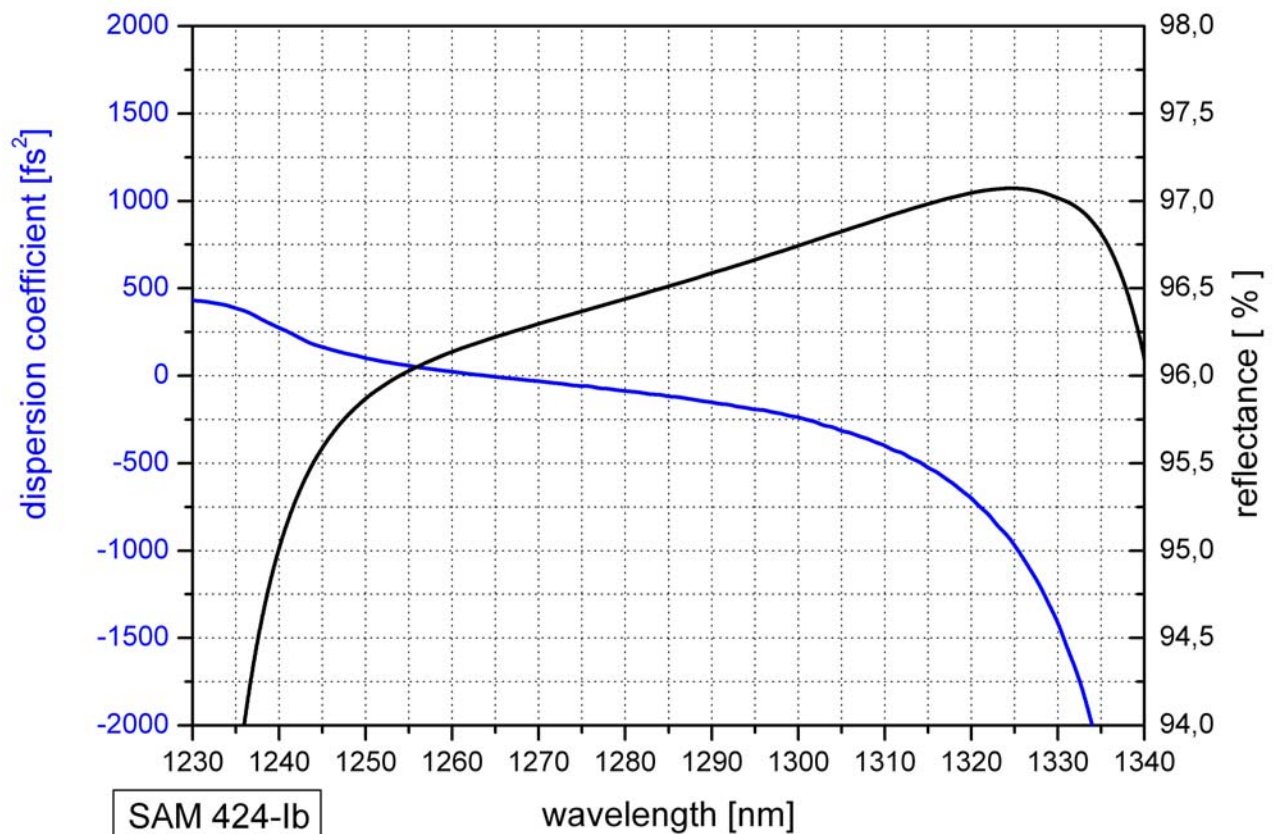


## SAM™ data sheet SAM-1300-4-x, $\lambda = 1300 \text{ nm}$

Laser wavelength	$\lambda = 1300 \text{ nm}$
High reflection band (R > 95%)	$\lambda = 1240 \dots 1340 \text{ nm}$
Saturable absorptance	$A_0 = 4 \%$
Saturation fluence	$\Phi_{\text{sat}} = 70 \mu\text{J}/\text{cm}^2$
Relaxation time constant	$\tau \leq 10 \text{ ps}$
Modulation depth	$\Delta R = 2.5 \%$
Chip area	4mm x 4mm; other dimensions on request
Chip thickness	400 $\mu\text{m}$ ; optional: 150 $\mu\text{m}$ on request
Protection	the SAM is protected with a dielectric front layer
Mounting of SAM-1300-4-x	denotes the type of mounting as follows:
x = 0	unmounted
x = 12.7 g	glued on a gold plated Cu-cylinder with 12.7 mm $\varnothing$
x = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm $\varnothing$
x = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm $\varnothing$
x = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm $\varnothing$
x = 25.0 w	soldered on a water cooled Cu-cylinder with 25.0 mm $\varnothing$
x = FC	mounted on a 1 m monomode fiber cable with FC connector

### Low intensity spectral reflectance and dispersion coefficient $D_2$



### Group Delay Dispersion (GDD)

Dispersion coefficient  $D_2(\omega) = \frac{\partial^2 \varphi}{\partial \omega^2}$  with  $\varphi$  - reflected phase

$\omega = 2\pi \frac{c}{\lambda}$  - angular frequency

### Third Order Dispersion (TOD)

Dispersion coefficient  $D_3(\omega) = \frac{\partial^3 \varphi}{\partial \omega^3}$

